NX3L4357

Low-ohmic single-pole triple-throw analog switch with enable input

Rev. 5 — 18 June 2012

Product data sheet

1. General description

The NX3L4357 is a low-ohmic single-pole triple-throw analog switch suitable for use as an analog or digital 3:1 multiplexer/demultiplexer. It has two digital select inputs (S0 and S1), one digital enable input (E), three independent inputs/outputs (Y0, Y1 and Y2) and a common input/output (Z). The device features a broadcast mode, when S0 and S1 are both high the signal applied to pin Z is passed to Y0, Y1 and Y2.

Schmitt trigger action at the digital inputs makes the circuit tolerant to slower input rise and fall times. Low threshold digital inputs allows this device to be driven by 1.8 V logic levels in 3.3 V applications without significant increase in supply current I_{CC} . This makes it possible for the NX3L4357 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation. The NX3L4357 allows signals with amplitude up to V_{CC} to be transmitted from Z to Yn or Yn to Z. Its low ON resistance (0.5 Ω) and flatness (0.13 Ω) ensures minimal attenuation and distortion of transmitted signals.

2. Features and benefits

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
 - 1.65 Ω (typical) at $V_{CC} = 1.4 \text{ V}$
 - 0.95 Ω (typical) at V_{CC} = 1.65 V
 - 0.55 Ω (typical) at $V_{CC} = 2.3 \text{ V}$
 - 0.50 Ω (typical) at $V_{CC} = 2.7 \text{ V}$
 - 0.50 Ω (typical) at V_{CC} = 4.3 V
- Break-before-make switching
- High noise immunity
- ESD protection:
 - ♦ HBM JESD22-A114F Class 3A exceeds 7500 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM AEC-Q100-011 revision B exceeds 1000 V
 - ◆ IEC61000-4-2 contact discharge exceeds 6000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78B Class II Level A
- 1.8 V control logic at V_{CC} = 3.6 V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V_{CC}
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



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3. Applications

- Cell phone
- PDA
- Portable media player

4. Ordering information

Table 1. Ordering information

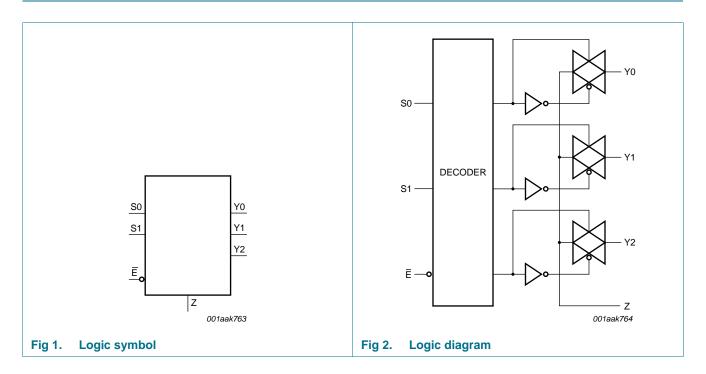
Type number	Package							
	Temperature range	Name	Description	Version				
NX3L4357GM	–40 °C to +125 °C	XQFN10	plastic extremely thin quad flatpackage; no leads; 10 terminals; body $2 \times 1.55 \times 0.5$ mm	SOT1049-3				

5. Marking

Table 2. Marking

Type number	Marking code
NX3L4357GM	D43

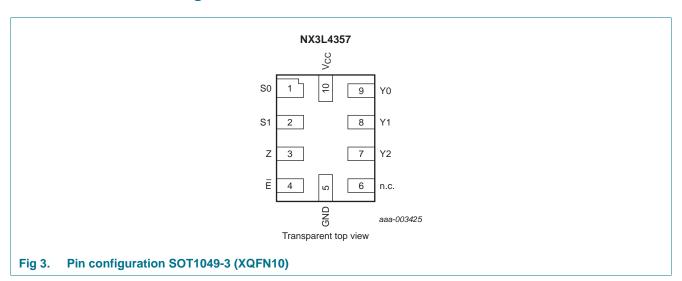
6. Functional diagram



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7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
S0	1	select input
S1	2	select input
Z	3	common output or input
Ē	4	enable input (active LOW)
GND	5	ground (0 V)
n.c.	6	not connected
Y2	7	independent input or output
Y1	8	independent input or output
Y0	9	independent input or output
V _{CC}	10	supply voltage

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8. Functional description

Table 4. Function table[1]

Ē	S 1	S0	Channel on
L	L	L	Y0 = Z
L	L	Н	Y1 = Z
L	Н	L	Y2 = Z
L	Н	Н	Y0, Y1, Y2 = Z (broadcast mode)
Н	X	X	switches off

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

		3 , , , , ,		.0	,
Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+4.6	V
V_{I}	input voltage	select input S0, S1 and \overline{E}	[<u>1</u>] -0.5	+4.6	V
V_{SW}	switch voltage		[<u>2</u>] -0.5	$V_{CC} + 0.5$	V
I _{IK}	input clamping current	$V_1 < -0.5 \text{ V}$	-50	-	mΑ
I _{SK}	switch clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±50	mΑ
I _{SW}	switch current	$V_{SW} > -0.5 \text{ V or } V_{SW} < V_{CC} + 0.5 \text{ V};$ source or sink current	-	±350	mA
		V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[3] _	250	mW

^[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

^[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

^[3] For XQFN10 packages: above 132 °C the value of Ptot derates linearly with 14.1 mW/K.

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10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		1.4	4.3	V
VI	input voltage	select input S0, S1 and \overline{E}	0	4.3	V
V_{SW}	switch voltage	switch input Y0, Y1 and Y2	<u>[1]</u> 0	V_{CC}	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 1.4 V to 4.3 V	[2] _	200	ns/V

^[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Yn. In this case, there is no limit for the voltage drop across the switch.

11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	T _{amb} =	–40 °C to	+125 °C	V V V V V V μA
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
V _{IH} HIGH-level		V _{CC} = 1.4 V to 1.6 V	0.9	-	-	0.9	-	-	V
	input voltage	V _{CC} = 1.65 V to 1.95 V	0.9	-	-	0.9	-	-	V
	V _{CC} = 2.3 V to 2.7 V	1.1	-	-	1.1	-	-	V	
		V _{CC} = 2.7 V to 3.6 V	1.3	-	-	1.3	-	-	V
		V _{CC} = 3.6 V to 4.3 V	1.4	-	-	1.4	-	-	V
V_{IL}	LOW-level	V _{CC} = 1.4 V to 1.6 V	-	-	0.3	-	0.3	0.3	V
	input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	0.4	-	0.4	0.3	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.5	-	0.5	0.4	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.5	-	0.5	0.5	V
		V _{CC} = 3.6 V to 4.3 V	-	-	0.6	-	0.6	0.6	V
I _I	input leakage current	select input S0, S1 and \overline{E} ; V _I = GND to 4.3 V; V _{CC} = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μΑ
I _{S(OFF)}	OFF-state leakage	port Y0, Y1 and Y2; see <u>Figure 4</u>							
	current	$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	-	±5	-	±10	±100	nA
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	±10	-	±50	±200	nΑ
$I_{S(ON)}$	ON-state	Z port; see Figure 5							
	leakage current	$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	-	±5	-	±20	±200	nΑ
	Current	$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	±10	-	±50	±400	nΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = GND$ or V_{CC}							
		$V_{CC} = 3.6 \text{ V}$	-	-	100	-	300	3000	nA
		V _{CC} = 4.3 V	-	-	150	-	500	5000	nA

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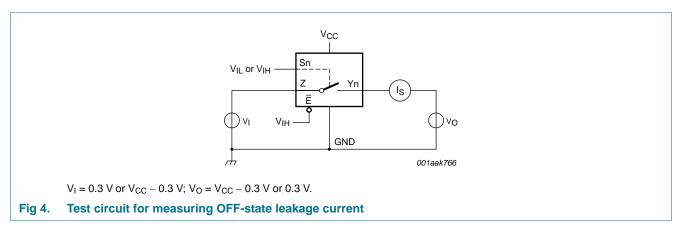
^[2] Applies to select input Sn signal levels.

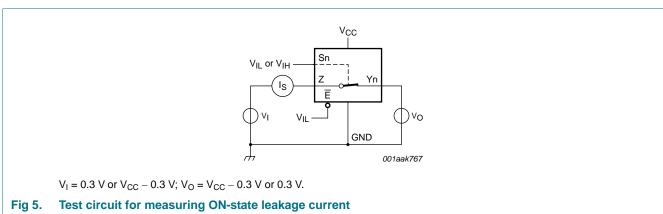
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Table 7. Static characteristics ...continued
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

	•								
Symbol	Parameter	Conditions	Tai	_{mb} = 25	°C	T _{amb} =	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
ΔI_{CC} additional	$V_{SW} = GND \text{ or } V_{CC}$	•		•	•				
	supply current	$V_{I} = 2.6 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	2.0	4.0	-	7	7	μΑ
		$V_{I} = 2.6 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	0.35	0.7	-	1	1	μΑ
		V _I = 1.8 V; V _{CC} = 4.3 V	-	7.0	10.0	-	15	15	μА
		V _I = 1.8 V; V _{CC} = 3.6 V	-	2.5	4.0	-	5	ax °C) Max (125 °C) 7 7 μA 1 1 μA 5 15 μA 5 5 μA 00 500 nA - - pF - - pF - - pF	μА
		V _I = 1.8 V; V _{CC} = 2.5 V	-	50	200	-	300	500	nA
C _I	input capacitance		-	1.0	-	-	-	-	pF
$C_{\text{S(OFF)}}$	OFF-state capacitance	port Y0, Y1 and Y2	-	35	-	-	-	-	pF
C _{S(ON)}	ON-state	port Z; broadcast mode	-	330	-	-	-	-	pF
	capacitance	port Y0, Y1 and Y2	-	170	-	-	-	-	pF

11.1 Test circuits





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11.2 ON resistance

Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 7 to Figure 13.

Symbol	Parameter	Conditions	Tan	1b = -	-40 °C to	+85 °C	T _{amb} = -40 °	C to +125 °C	Unit
			Mi	n	Typ[1]	Max	Min	Max	
R _{ON(peak)}	ON resistance (peak)	port Y0, Y1 and Y2; $V_I = GND$ to V_{CC} ; $I_{SW} = 100$ mA; see Figure 6							'
		V _{CC} = 1.4 V	-		1.6	3.7	-	4.1	Ω
		V _{CC} = 1.65 V	-		1.0	1.6	-	1.7	Ω
		$V_{CC} = 2.3 \text{ V}$	-		0.55	0.8	-	0.9	Ω
		$V_{CC} = 2.7 \text{ V}$	-		0.5	0.75	-	0.9	Ω
		$V_{CC} = 4.3 \text{ V}$	-		0.5	0.75	-	0.9	Ω
ΔR_{ON}	ON resistance mismatch between channels	$V_I = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}$	[2]						
		$V_{CC} = 1.4 \text{ V}$	-		0.20	0.35	-	0.35	Ω
		$V_{CC} = 1.65 \text{ V}$	-		0.20	0.25	-	0.30	Ω
		$V_{CC} = 2.3 \text{ V}$	-		0.09	0.13	-	0.15	Ω
		$V_{CC} = 2.7 \text{ V}$	-		0.09	0.13	-	0.15	Ω
		$V_{CC} = 4.3 \text{ V}$	-		0.09	0.13	-	0.15	Ω
R _{ON(flat)}	ON resistance (flatness)	port Y0, Y1 and Y2; $V_I = GND$ to V_{CC} ; $I_{SW} = 100 \text{ mA}$	[3]						
		V _{CC} = 1.4 V	-		1.05	3.35	-	3.65	Ω 0.30 $Ω$ 0.15 $Ω$ 0.15 $Ω$ 0.15 $Ω$
		$V_{CC} = 1.65 \text{ V}$	-		0.55	1.25	-	1.35	Ω
		$V_{CC} = 2.3 \text{ V}$	-		0.20	0.35	-	0.40	Ω
		$V_{CC} = 2.7 \text{ V}$	-		0.18	0.35	-	0.40	Ω
		$V_{CC} = 4.3 \text{ V}$	-		0.23	0.40	-	0.45	Ω

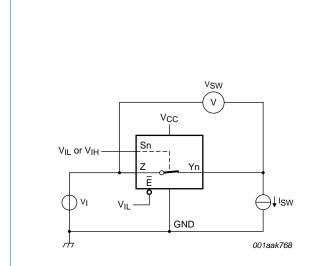
^[1] Typical values are measured at T_{amb} = 25 °C.

^[2] Measured at identical V_{CC} , temperature and input voltage.

^[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.

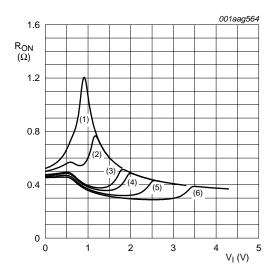
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11.3 ON resistance test circuit and graphs



 $R_{ON} = V_{SW} / I_{SW}$

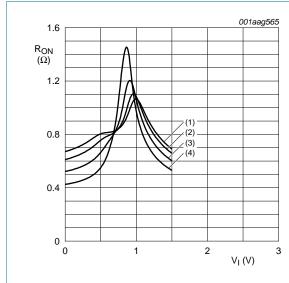
Fig 6. Test circuit for measuring ON resistance



- (1) $V_{CC} = 1.5 \text{ V}.$
- (2) $V_{CC} = 1.8 \text{ V}.$
- (3) $V_{CC} = 2.5 \text{ V}.$
- (4) $V_{CC} = 2.7 \text{ V}.$
- (5) $V_{CC} = 3.3 \text{ V}.$ (6) $V_{CC} = 4.3 \text{ V}.$
 - Measured at T_{amb} = 25 °C.

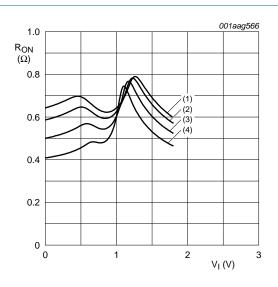
Fig 7. Typical ON resistance as a function of input voltage (Yn port)

Low-ohmic single-pole triple-throw analog switch with enable input



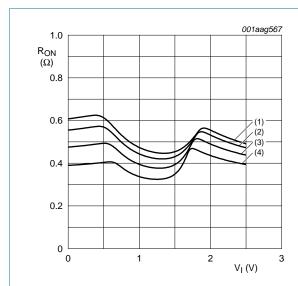
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 8. ON resistance as a function of input voltage; $V_{CC} = 1.5 \text{ V (Yn port)}$



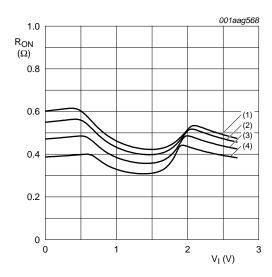
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 9. ON resistance as a function of input voltage; $V_{CC} = 1.8 \text{ V (Yn port)}$



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

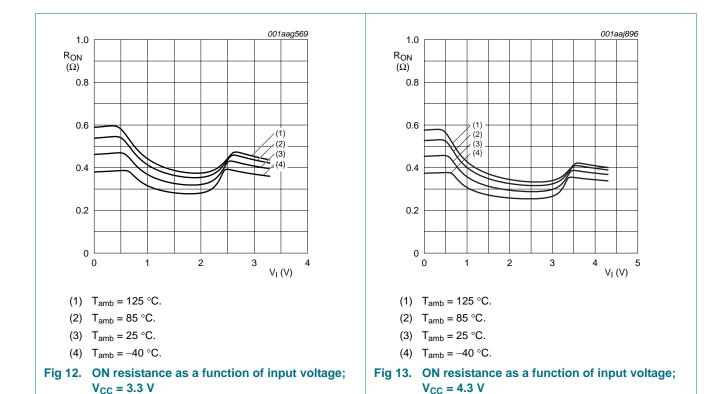
Fig 10. ON resistance as a function of input voltage; $V_{CC} = 2.5 \text{ V (Yn port)}$



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 11. ON resistance as a function of input voltage; $V_{CC} = 2.7 \text{ V (Yn port)}$

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12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Figure 16.

Symbol	Parameter Conditions		Ta	_{mb} = 25	°C	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$			Unit
			Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
t _{en}	enable time	E, Sn to Z or Yn; see Figure 14			•				
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	50	100	-	120	125	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	36	75	-	85	95	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	24	50	-	55	60	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	22	45	-	45	50	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	22	45	-	45	50	ns
t _{dis}	disable time	E, Sn to Z or Yn; see Figure 14							
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	32	80	-	90	105	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	20	65	-	70	75	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	12	30	-	35	40	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	10	25	-	30	35	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	10	25	-	30	35	ns

Low-ohmic single-pole triple-throw analog switch with enable input

 Table 9.
 Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Figure 16.

Symbol	bol Parameter Conditions		Ta	_{mb} = 25	°C	T _{amb} =	–40 °C to	40 °C to +125 °C	
			Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
t _{b-m}	break-before-make	see Figure 15 [2]							
time	time	$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	19	-	9	-	-	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	17	-	7	-	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	13	-	4	-	-	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	10	-	3	-	-	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	10	-	2	-	-	ns

^[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

12.1 Waveforms and test circuits

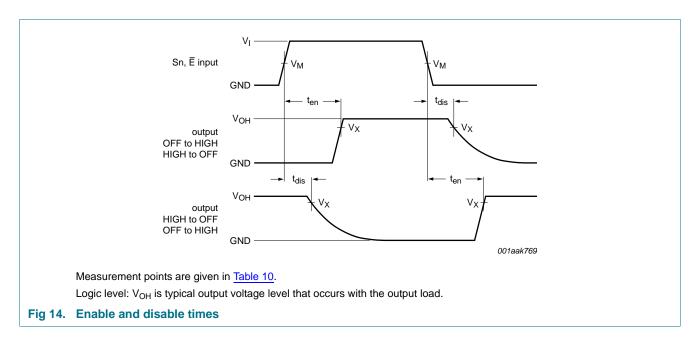
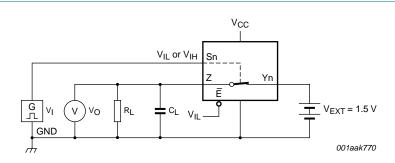


Table 10. Measurement points

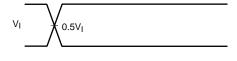
Supply voltage	Input	Output
V _{CC}	V _M	V _X
1.4 V to 4.3 V	0.5V _{CC}	0.9V _{OH}

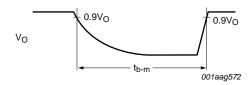
^[2] Break-before-make guaranteed by design.

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a. Test circuit

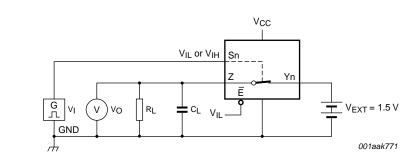




b. Input and output measurement points

V_I may be connected to S0 or S1.

Fig 15. Test circuit for measuring break-before-make timing



Test data is given in Table 11.

 V_I may be connected to Sn or \overline{E} .

Definitions test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 V_{EXT} = External voltage for measuring switching times.

Fig 16. Load circuit for switching times

Table 11. Test data

Supply voltage	Input		Load	
V _{CC}	VI	t _r , t _f	CL	R _L
1.4 V to 4.3 V	V_{CC}	≤ 2.5 ns	35 pF	50 Ω

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Low-ohmic single-pole triple-throw analog switch with enable input

12.2 Additional dynamic characteristics

Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_l = \text{GND}$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 2.5$ ns.

Symbol	Parameter	Conditions		T _{amb} = 25 °C			Unit
				Min	Тур	Max	
THD total harmonic distortion		f_i = 20 Hz to 20 kHz; R_L = 32 Ω ; see Figure 17	<u>[1]</u>			'	
	distortion	$V_{CC} = 1.4 \text{ V}; V_I = 1 \text{ V (p-p)}$		-	0.15	-	%
		$V_{CC} = 1.65 \text{ V}; V_I = 1.2 \text{ V (p-p)}$		-	0.10	-	%
		$V_{CC} = 2.3 \text{ V}; V_I = 1.5 \text{ V (p-p)}$		-	0.02	-	%
		$V_{CC} = 2.7 \text{ V}; V_1 = 2 \text{ V (p-p)}$		-	0.02	-	%
		$V_{CC} = 4.3 \text{ V}; V_1 = 2 \text{ V (p-p)}$		-	0.02	-	%
		$V_{CC} = 3.0 \text{ V}; V_{I} = 1 \text{ V (p-p)}; R_{L} = 600 \Omega$		-	0.01	-	%
f _(-3dB)	-3 dB frequency	$R_L = 50 \Omega$; see Figure 18	<u>[1]</u>				
	response	port Y0, Y1 or Y2; V _{CC} = 1.4 V to 4.3 V		-	30	-	MHz
		port Y0, Y1 and Y2; V _{CC} = 1.4 V to 4.3 V		-	20	-	MHz
$\alpha_{\rm iso}$ isolation (OFF-state	isolation (OFF-state)	f_i = 100 kHz; R_L = 50 Ω ; see Figure 19	<u>[1]</u>				
		V _{CC} = 1.4 V to 4.3 V		-	-90	-	dB
V _{ct} crosstalk voltage	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$; $C_L = 50 \text{ pF}$; $R_L = 50 \Omega$; see Figure 20					
		V _{CC} = 1.4 V to 3.6 V		-	0.21	-	V
		V _{CC} = 3.6 V to 4.3 V		-	0.30	-	V
Xtalk crosstalk		between switches; $f_i = 100 \text{ kHz}$; $R_L = 50 \Omega$; see Figure 21	[1]				
		V _{CC} = 1.4 V to 4.3 V		-	-90	-	dB
Q _{inj} (charge injection	f_i = 1 MHz; C_L = 0.1 nF; R_L = 1 M Ω ; V_{gen} = 0 V; R_{gen} = 0 Ω ; see <u>Figure 22</u>					
		V _{CC} = 1.5 V		-	10	-	рС
		V _{CC} = 1.8 V		-	15	-	рС
		V _{CC} = 2.5 V		-	26	-	рС
		$V_{CC} = 3.3 \text{ V}$		-	36	-	рС
		V _{CC} = 4.3 V		-	50	-	рС

^[1] f_i is biased at $0.5V_{CC}$.

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12.3 Test circuits

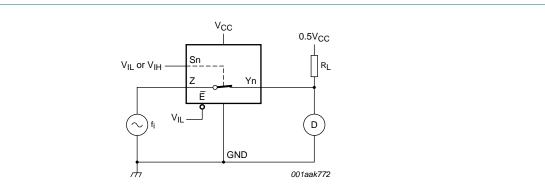
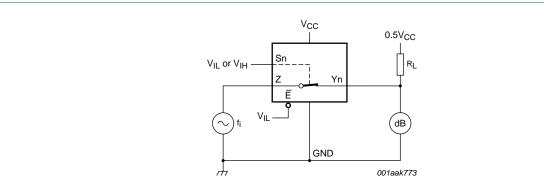
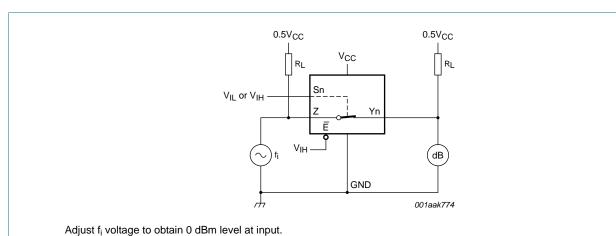


Fig 17. Test circuit for measuring total harmonic distortion



Adjust f_i voltage to obtain 0 dBm level at output. Increase f_i frequency until dB meter reads –3 dB.

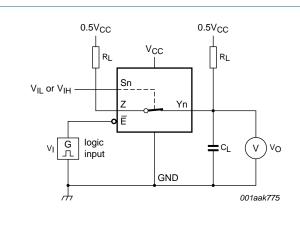
Fig 18. Test circuit for measuring the frequency response when channel is in ON-state



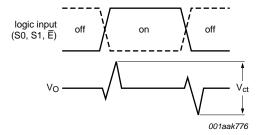
rajust i remage to obtain o azim love at input

Fig 19. Test circuit for measuring isolation (OFF-state)

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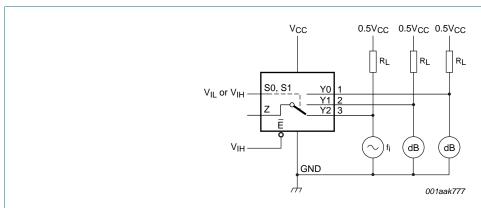


a. Test circuit



b. Input and output pulse definitions V_I may be connected to Sn or \overline{E} .

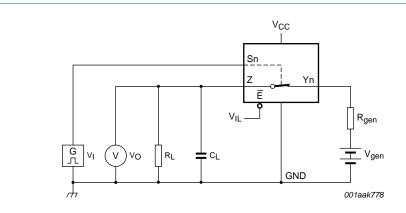
Fig 20. Test circuit for measuring crosstalk voltage between digital inputs and switch



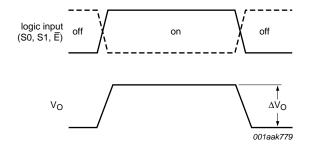
 f_i may be connected to Y0, Y1 or Y2.

Fig 21. Test circuit for measuring crosstalk between switches

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a. Test circuit



b. Input and output pulse definitions

 V_I may be connected to Sn or \overline{E} .

Definition: $Q_{inj} = \Delta V_O \times C_L$.

 ΔV_{O} = output voltage variation.

 R_{gen} = generator resistance.

 V_{gen} = generator voltage.

Fig 22. Test circuit for measuring charge injection

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13. Package outline

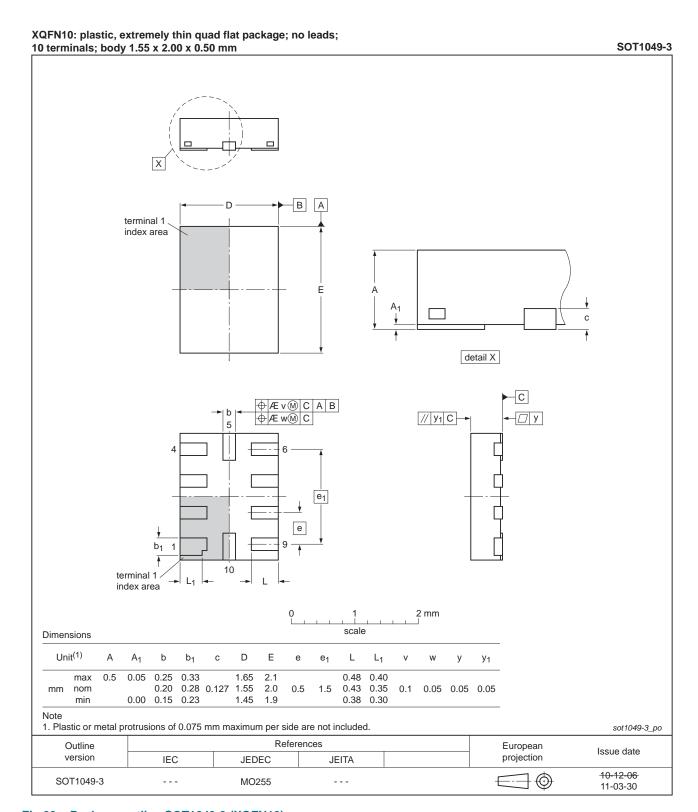


Fig 23. Package outline SOT1049-3 (XQFN10)

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14. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

15. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L4357 v.5	20120618	Product data sheet	-	NX3L4357 v.4
Modifications:	 Package outl 	ine drawing SOT1049-2 chanç	ged to SOT1049-3 (<u>Fig</u>	gure 23).
NX3L4357 v.4	20111107	Product data sheet	-	NX3L4357 v.3
Modifications:	 Legal pages 	updated.		
NX3L4357 v.3	20101228	Product data sheet	-	NX3L4357 v.2
NX3L4357 v.2	20100428	Product data sheet	-	NX3L4357 v.1
NX3L4357 v.1	20091019	Product data sheet	-	-

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16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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